

# Polymorphism of Ba<sub>2</sub>SiP<sub>4</sub>

Arthur Haffner,<sup>[a]</sup> Valentin Weippert,<sup>[a]</sup> and Dirk Johrendt<sup>\*[a]</sup>

*Dedicated to Professor Hans-Jörg Deiseroth on the Occasion of his 75th Birthday*

**Abstract.** The three-dimensional SiP<sub>4</sub> network in the known phosphidosilicate Ba<sub>2</sub>SiP<sub>4</sub>-*tI28* is analogous to β-Cristobalite if oxygen is formally replaced by P–P dimers. Here we report a second polymorph Ba<sub>2</sub>SiP<sub>4</sub>-*oP56* [*Pnma*, *a* = 12.3710(4) Å, *b* = 14.6296(7) Å, *c* = 7.9783(3) Å; *Z* = 8] with chains of SiP<sub>4</sub> tetrahedra connected by P–P

bonds, reminiscent to the elusive fibrous SiO<sub>2</sub>. Ba<sub>2</sub>SiP<sub>4</sub> is enantiotropic. The high temperature polymorph Ba<sub>2</sub>SiP<sub>4</sub>-*oP56* transforms to the low-temperature phase Ba<sub>2</sub>SiP<sub>4</sub>-*tI28* at 650 °C and reconstructs to the high-temperature modification at 1100 °C. DFT calculations predict an indirect optical bandgap of about 1.7 eV.

## Introduction

Phosphidosilicates are known since the 1980s and attract anew considerable interest due to its broad structural variety involving compounds with versatile properties. The structures based on SiP<sub>4</sub> tetrahedra as anionic basic building unit are closely related to oxido- and nitridosilicates indicating a large structural variety. The nesosilicates Li<sub>8</sub>SiP<sub>4</sub>,<sup>[1]</sup> EA<sub>4</sub>SiP<sub>4</sub> (EA = Ca, Sr, Ba)<sup>[2]</sup> or Na<sub>4</sub>EA<sub>2</sub>SiP<sub>4</sub> (EA = Ca, Sr, Eu)<sup>[3]</sup> are rare examples of isolated highly charged [SiP<sub>4</sub>]<sup>8-</sup> anions. More common are SiP<sub>4</sub> anions with reduced charge density achieved by different condensation degrees leading to chains, layers, or three-dimensional network motifs. A<sub>10</sub>Si<sub>2</sub>P<sub>6</sub> (A = Li, Na)<sup>[4]</sup> exhibits edge-shared [Si<sub>2</sub>P<sub>6</sub>]<sup>10-</sup> entities whereas the charge density is decreased furthermore by edge condensation of these units to infinite [SiP<sub>2</sub>]<sup>2-</sup> chains found in K<sub>2</sub>SiP<sub>2</sub>.<sup>[5]</sup> Interestingly, to date layered phosphidosilicates were only observed with supertetrahedral entities constituted of vertex sharing SiP<sub>4</sub> tetrahedra in CaSiP<sub>2</sub>,<sup>[6]</sup> and KSi<sub>2</sub>P<sub>3</sub>.<sup>[7]</sup> In contrast, the introduction of small and weak electronegative metals yields three-dimensional structures of vertex-shared tetrahedra<sup>[8]</sup> or supertetrahedra with sizes ranged from T2 to T5<sup>[9]</sup> and the feature of supertetrahedral fusion in Li<sub>2</sub>SiP<sub>2</sub>, LiSi<sub>2</sub>P<sub>3</sub><sup>[10]</sup> and Na<sub>23</sub>Si<sub>9n+19</sub>P<sub>12n+33</sub> with *n* = 0–3.<sup>[11]</sup> To the best of our knowledge this uncommon condensation mode was sparsely observed only in KSi<sub>2</sub>P<sub>3</sub>,<sup>[7]</sup> B<sub>2</sub>S<sub>3</sub>,<sup>[12]</sup> Li<sub>9</sub>B<sub>19</sub>S<sub>33</sub>,<sup>[13]</sup> M<sub>15</sub>Tr<sub>22</sub>As<sub>32</sub> and M<sub>3</sub>Ga<sub>6</sub>As<sub>8</sub> (M = Sr, Eu; Tr = Ga, In)<sup>[14]</sup> and a few other mixed-metal T3 chalcogenides.<sup>[15]</sup>

The possibility of the formation of homonuclear phosphorus bonding distinguishes the family of phosphidosilicates from the oxido- and nitridosilicates. Isolated P–P bonding was

described in AlSiP<sub>3</sub>,<sup>[16]</sup> Ca<sub>3</sub>Si<sub>8</sub>P<sub>14</sub>,<sup>[6]</sup> Ba<sub>2</sub>Si<sub>3</sub>P<sub>6</sub><sup>[17]</sup> and Ba<sub>4</sub>Si<sub>3</sub>P<sub>8</sub>,<sup>[18]</sup> for example, whereas in LaSi<sub>2</sub>P<sub>6</sub> up to four different polyphosphide anions (P<sub>*n*</sub>)<sup>-(*n*+2)</sup> with *n* = 3–6 and in Li<sub>3</sub>Si<sub>3</sub>P<sub>7</sub><sup>[4a]</sup> polyphosphide chains exist. Tetragonal Ba<sub>2</sub>SiP<sub>4</sub>-*tI28*<sup>[19]</sup> is the first example where all SiP<sub>4</sub> tetrahedra are connected by P–P bonds. Currently the Ba-Si-P ternary system attracts attention regarding possible NLO and thermoelectric properties.<sup>[17]</sup> Therefore, we focused upon this compounds and found the high-temperature enantiotropic polymorph Ba<sub>2</sub>SiP<sub>4</sub>-*oP56*, in which all SiP<sub>4</sub> tetrahedra are linked by homonuclear phosphorus bonds, as well, being the second example for this structure motif.

## Results and Discussion

Ba<sub>2</sub>SiP<sub>4</sub>-*oP56* was synthesized by solid-state reactions of stoichiometric amounts of respective elements under inert conditions revealing air sensitive polycrystalline black powders. Single crystals suitable for single-crystal X-ray diffraction were selected under dried paraffin oil. The compound crystallizes in a primitive orthorhombic unit cell in space group

**Table 1.** Crystallographic data of Ba<sub>2</sub>SiP<sub>4</sub>-*oP56*.

	Ba <sub>2</sub> SiP <sub>4</sub>
space group	<i>Pnma</i> (no. 62)
<i>a</i> / Å	12.3710(4)
<i>b</i> / Å	14.6296(7)
<i>c</i> / Å	7.9783(3)
<i>V</i> <sub>cell</sub> / Å <sup>3</sup>	1443.93(10)
<i>Z</i>	8
$\rho_{\text{X-ray}}$ / g·cm <sup>-3</sup>	3.925
$\mu$ / mm <sup>-1</sup>	11.773
$\Theta$ -range / °	2.785–30.527
Reflections measured	14530
Independent reflections	2286
Parameters	67
<i>R</i> <sub>σ</sub>	0.0343
<i>R</i> <sub>int</sub>	0.0596
<i>R</i> <sub>1</sub> [F <sup>2</sup> > 2σ(F <sup>2</sup> )] / all	0.0281 / 0.0448
<i>wR</i> <sub>2</sub> [F <sup>2</sup> > 2σ(F <sup>2</sup> )] / all	0.0470 / 0.0509
Goof	1.095
$\Delta\rho$ max/min / e·Å <sup>-3</sup>	1.536 / -1.293

\* Prof. Dr. D. Johrendt  
E-Mail: johrendt@lmu.de

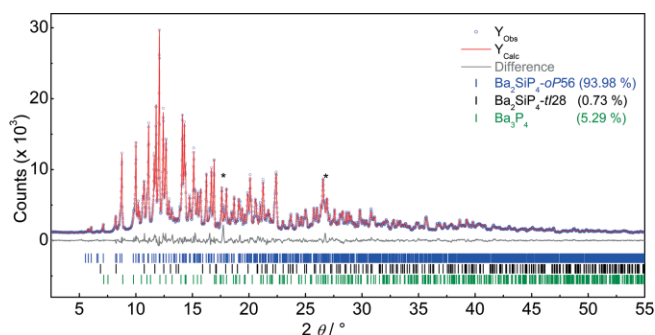
[a] Department of Chemistry  
Ludwig-Maximilians-University of Munich  
Butenandtstrasse 5–13 (D)  
81377 Munich, Germany

© 2019 The Authors. Published by Wiley-VCH Verlag GmbH & Co. KGaA. • This is an open access article under the terms of the Creative Commons Attribution-NonCommercial-NoDerivs License, which permits use and distribution in any medium, provided the original work is properly cited, the use is non-commercial and no modifications or adaptations are made.

**Table 2.** Fractional coordinates, Wyckoff positions, and equivalent displacement parameters of Ba<sub>2</sub>SiP<sub>4</sub>-oP56.

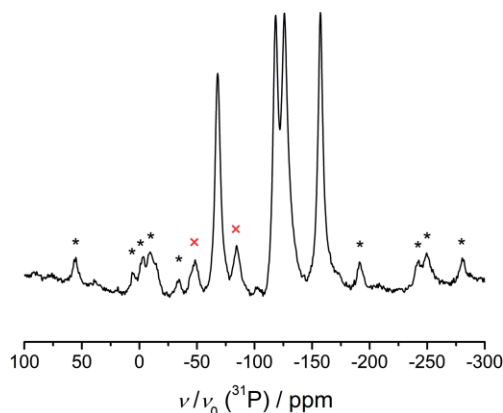
Atom	Wyckoff position	x	y	z	$U_{eq}/\text{\AA}^2$
Ba1	8d	0.34858 (2)	0.51347(2)	0.38205(4)	0.01148(7)
Ba2	4c	0.26291(4)	1/4	0.22464(6)	0.01343(9)
Ba3	4c	0.43469(4)	1/4	0.72852(6)	0.0173(1)
Si1	8d	0.04023(11)	0.11551(10)	0.38639(17)	0.0094(2)
P1	8d	0.01981(11)	0.17373(9)	0.12824(17)	0.0116(2)
P2	8d	0.09964(10)	0.51730(9)	0.28240(15)	0.0108(2)
P3	8d	0.16274(11)	0.17243(10)	0.57072(17)	0.0136(3)
P4	8d	0.37387(10)	0.10051(9)	0.00761(16)	0.0104(2)

*Pnma* with lattice parameters  $a = 12.3710(4)$  Å,  $b = 14.6296(7)$  Å, and  $c = 7.9783(3)$  Å. The structure was solved and refined using the SHELX<sup>[20]</sup> package. Crystallographic data of Ba<sub>2</sub>SiP<sub>4</sub>-oP56 are given in Table 1, fractional coordinates and equivalent displacement parameters in Table 2. Based on this data the powder pattern of a polycrystalline sample was indexed and refined yielding in about 94 wt-% of the targeted phase with small impurities of the low-temperature polymorph Ba<sub>2</sub>SiP<sub>4</sub>-tI28,<sup>[19]</sup> Ba<sub>3</sub>P<sub>4</sub><sup>[21]</sup> and a minor unidentified phase (Figure 1).



**Figure 1.** X-ray powder pattern of the Ba<sub>2</sub>SiP<sub>4</sub>-oP56 sample (blue circles) with Rietveld fit (red line) and difference (grey line). Small amounts of Ba<sub>2</sub>SiP<sub>4</sub>-tI28 and Ba<sub>3</sub>P<sub>4</sub>, beside an unknown impurity, marked with asterisks, were detected.

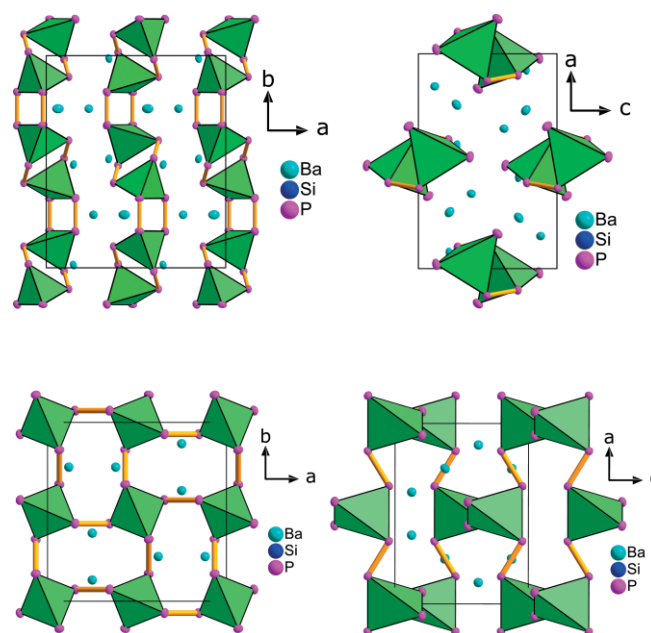
The polycrystalline sample was further investigated by solid-state MAS-NMR and EDX, confirming the elemental composition. Figure 2 shows the <sup>31</sup>P spectrum with four distinct



**Figure 2.** <sup>31</sup>P solid-state MAS-NMR spectrum of Ba<sub>2</sub>SiP<sub>4</sub>-oP56. Rotation side bands are marked with asterisks and resonance frequencies of the Ba<sub>3</sub>P<sub>4</sub> impurity with red crosses.

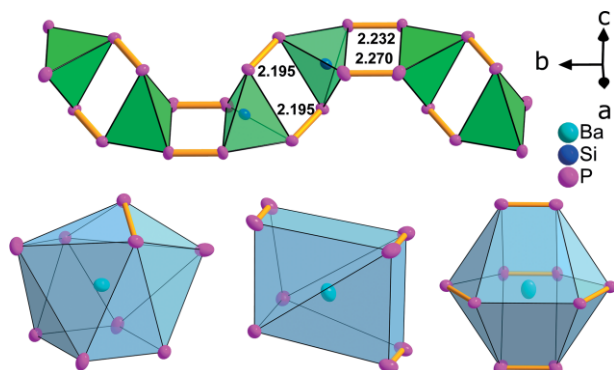
resonance frequencies at  $\delta$  (P) = -67.98, -118.33, -125.92, -157.23 ppm, each with the same intensity indicating four magnetically inequivalent phosphorus atoms with the same multiplicity, which is in accordance with the single crystal structure. The examined sample contains 5 wt-% Ba<sub>3</sub>P<sub>4</sub> in Sr<sub>3</sub>As<sub>4</sub> type structure with two crystallographically different phosphorus atoms.<sup>[21]</sup> This impurity is visible in the <sup>31</sup>P NMR spectrum with two additional resonance frequencies at  $\delta$  (P) = -48.35 and -84.40 ppm (see Figure 2, red crosses).

Ba<sub>2</sub>SiP<sub>4</sub>-oP56 crystallizes in a new structure type with a unique structural motif composed of SiP<sub>4</sub> tetrahedra. As in Ba<sub>2</sub>SiP<sub>4</sub>-tI28, P–P bonds [ $\text{O}d(\text{P}-\text{P}) = 2.23$  Å] link all SiP<sub>4</sub> tetrahedra, but here the connectivity generates chains along the *b* axis (Figure 3). The chains form a distorted hexagonal rod packing, similar to the chains of edge-sharing SiS<sub>4/2</sub> tetrahedra in SiS<sub>2</sub>.<sup>[22]</sup> As we mentioned earlier, the three-dimensional network in Ba<sub>2</sub>SiP<sub>4</sub>-tI28 is analogous to  $\beta$ -Cristobalite, if one replaces the oxygen atoms in SiO<sub>2</sub> by P<sub>2</sub> dimers. In this sense, the new chain structure of Ba<sub>2</sub>SiP<sub>4</sub>-oP56 would be the analogue of the fibrous SiO<sub>2</sub>, which is still elusive.<sup>[23]</sup>



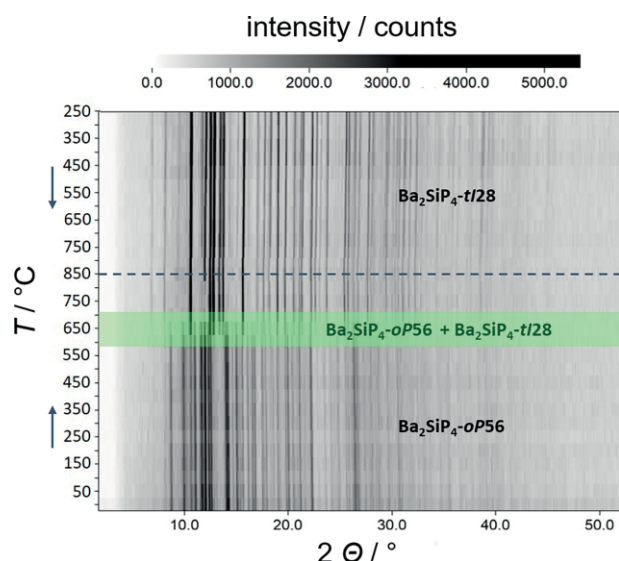
**Figure 3.** Crystal structure of Ba<sub>2</sub>SiP<sub>4</sub>-oP56 with view along [001] (top, left) and along [010] (top, right) and Ba<sub>2</sub>SiP<sub>4</sub>-tI28 with respective viewing directions (bottom). Ellipsoids are drawn with 90% probability.

The  $\text{Ba}^{2+}$  cations are located between the anionic chains in strongly distorted polyhedra, which are gyro-elongated square pyramids (Ba1) with one, cubes (Ba2) with three or elongated square bipyramids (Ba3) with five homonuclear phosphorus bonds as depicted in Figure 4.



**Figure 4.**  $\frac{1}{2}[\text{SiP}_4]^{4-}$  chain motif of *pseudo* edge-condensed  $\text{SiP}_4$  tetrahedra (top) and Ba coordinations containing homonuclear phosphorus bonds of Ba1 (left), Ba2 (middle) and Ba3 (right). All  $\text{BaP}_x$  polyhedra are strongly distorted.

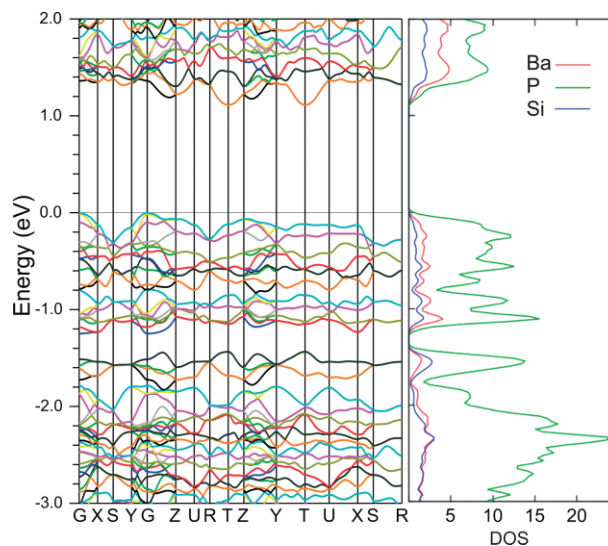
$\text{Ba}_2\text{SiP}_4\text{-}oP56$  does not form if the solid state reactions are carried out at increased temperatures of  $1100\text{ }^\circ\text{C}$  with the slow cooling rates used for  $\text{Ba}_2\text{SiP}_4\text{-}tI28$ .<sup>[19]</sup> A nearly phase-pure sample could only be obtained by faster cooling rates from  $-10\text{ K}\cdot\text{h}^{-1}$  to  $-50\text{ K}\cdot\text{h}^{-1}$ . We examined the phase transition of  $\text{Ba}_2\text{SiP}_4\text{-}oP56$  to  $\text{Ba}_2\text{SiP}_4\text{-}tI28$  by high-temperature powder diffraction yielding no transition until about  $600\text{ }^\circ\text{C}$ , before a mixture of both modifications occurs near  $650\text{ }^\circ\text{C}$ . At  $700\text{ }^\circ\text{C}$ ,  $\text{Ba}_2\text{SiP}_4\text{-}oP56$  is almost completely transformed to  $\text{Ba}_2\text{SiP}_4\text{-}tI28$ , which persists upon cooling to room temperature (Figure 5). The additional reflection at about  $2\theta = 12^\circ$  above  $850\text{ }^\circ\text{C}$  is probably caused by crystallizing of the silica capil-



**Figure 5.** High-temperature powder diffraction pattern of  $\text{Ba}_2\text{SiP}_4$ . The sample was heated to  $850\text{ }^\circ\text{C}$  (marked with dashed line) and then cooled to  $250\text{ }^\circ\text{C}$ . Phase transition occurs between  $600$  and  $700\text{ }^\circ\text{C}$  (highlighted in green).

lary. On the other hand  $\text{Ba}_2\text{SiP}_4\text{-}oP56$  can also be obtained from  $\text{Ba}_2\text{SiP}_4\text{-}tI28$  if the same heating protocol is applied with faster cooling, thus  $\text{Ba}_2\text{SiP}_4$  is enantiotropic with reconstructive phase transitions.

For the estimation of the electronic properties of  $\text{Ba}_2\text{SiP}_4\text{-}oP56$  DFT calculations were performed. Figure 6 shows the electronic band structure and the atom-resolved density-of-states for  $\text{Ba}_2\text{SiP}_4\text{-}oP56$ . The valence band is dominated by the P-3p states with some contributions of Si-3p and Ba-5d. The energy gap is  $1.11\text{ eV}$  using the PBE and increases to  $1.65\text{ eV}$  with the mBJ functional. The valence band maximum is located at the  $\Gamma$ -point in the Brillouin zone and the conduction band minimum occurs at  $T$ , which means that the calculation predicts an indirect bandgap.



**Figure 6.** Electronic band structure (left) and atom-resolved DOS (right) for  $\text{Ba}_2\text{SiP}_4\text{-}oP56$ . The energy zero is taken at the Fermi level.

## Conclusions

$\text{Ba}_2\text{SiP}_4\text{-}oP56$  crystallizes in a new structure type constituting the second example of a phosphidosilicate with all phosphorus atoms connected by P–P bonds. The crystal structure comprises  $\text{SiP}_4$  tetrahedra bridged via P–P bonds, leading to  $\frac{1}{2}[\text{SiP}_4]^{4-}$  chains. While the network of tetragonal polymorph  $\text{Ba}_2\text{SiP}_4\text{-}tI28$  is analogous to the  $\beta$ -Cristobalite type if one replaces oxygen by  $\text{P}_2$  dimers, the chains in the new compound  $\text{Ba}_2\text{SiP}_4\text{-}oP56$  are analogous to  $\text{SiS}_2$ , and reminiscent to the elusive fibrous  $\text{SiO}_2$ . A phase transition from  $\text{Ba}_2\text{SiP}_4\text{-}oP56$  to  $\text{Ba}_2\text{SiP}_4\text{-}tI28$  occurs at around  $650\text{ }^\circ\text{C}$  whereas we expect the re-transition well beyond  $1000\text{ }^\circ\text{C}$ , which we were not able to determine. Solid-state MAS-NMR data and its EDX fully confirm the structure. DFT calculations reveal an indirect bandgap of around  $1.7\text{ eV}$  in agreement with the black color of the compound.

## Experimental Section

**Synthesis:**  $\text{Ba}_2\text{SiP}_4\text{-}oP56$  was obtained by two different routes. Either a stoichiometric mixture of respective elements (Ba, 99.99%, Sigma

Aldrich; Si, 99.8%, SMART ELEMENTS; P<sub>red.</sub> > 99%, CHEMPUR) or a phase-pure sample of Ba<sub>2</sub>SiP<sub>4</sub>-tI28 was heated to 1100 °C with a 50 K·h<sup>-1</sup> rate for the elemental or with a 200 K·h<sup>-1</sup> rate for the Ba<sub>2</sub>SiP<sub>4</sub>-tI28 route in alumina crucibles welded in argon filled silica ampoules. This temperature was held for 40 h before it was decreased to 450 °C with a relatively fast cooling rate of -50 K·h<sup>-1</sup>. After cooling to room temperature the targeted product was received as polycrystalline and air sensitive black powder.

**Single-Crystal X-ray Diffraction:** Due to air sensitivity single crystals of sufficient quality were selected under dried paraffin oil and transferred in oil filled and fused Hilgenberg glass capillaries with 0.2 mm in diameter. Diffraction data were collected by a Bruker D8 Venture diffractometer with a rotating anode, Göbel mirror optics and a Photon II detector. Reflection indexing, data reduction and absorption correction were processed by the Bruker software APEX3.<sup>[24]</sup> Based on systematically absent reflections the space group of Ba<sub>2</sub>SiP<sub>4</sub>-oP56 was identified with XPREP.<sup>[25]</sup> Final solution and refinement of the crystal structure were performed with direct methods implemented in the SHELX software package.<sup>[20]</sup> For visualization of the crystal structure Diamond<sup>[26]</sup> software was chosen.

**Powder X-ray Diffraction:** A ground sample was loaded and sealed in a glass capillary with 0.2 mm in diameter (Hilgenberg GmbH) to avoid hydrolysis. Diffraction patterns were recorded on a Stadi-P powder diffractometer in Debye-Scherrer setup (STOE & Cie GmbH) equipped with a Ge monochromator, a Mythen 1 K detector (Dectris) and Mo-K<sub>α1</sub> radiation. Diffractograms were indexed and refined using the single-crystal structure model and the Rietveld method implemented in the TOPAS<sup>[27]</sup> software.

**Temperature-Dependent Powder X-ray Diffraction:** For the investigation of the phase transition a ground sample was loaded into a silica capillary with 0.5 mm in diameter (Hilgenberg GmbH) and sealed with grease for pressure compensation while heating. Data were collected under argon atmosphere also on a Stadi-P diffractometer (STOE & Cie) with a Ge monochromator, an IP-PSD detector, a resistance graphite furnace and Mo-K<sub>α1</sub> radiation. The sample was heated to 850 °C and cooled to room temperature in steps of 50 °C with a 5 K·min<sup>-1</sup> rate. At each step, the temperature was kept constant and a diffraction pattern was collected. We were not able to measure the retransition from Ba<sub>2</sub>SiP<sub>4</sub>-tI28 to Ba<sub>2</sub>SiP<sub>4</sub>-oP56 beyond 1000 °C because of the limited chemical stability of the silica capillaries.

**Solid-State MAS-NMR Spectroscopy:** For the nuclear magnetic resonance spectrum of the <sup>31</sup>P nuclei a polycrystalline sample of Ba<sub>2</sub>SiP<sub>4</sub>-oP56 was loaded into a commercial zirconia rotor with 2.5 mm in diameter and placed into a Bruker Avance III 500 spectrometer device with a magnetic field of 11.74 T. The sample was rotated under MAS conditions with a frequency of 25 kHz and a Larmor frequency of ν<sub>0</sub> (<sup>31</sup>P) = 202.5 MHz.

**EDX Analysis:** For elemental analysis, a sample was prepared under argon atmosphere onto adhesive and conductive carbon pads, which were inserted into an EVO-MA 10 (Zeiss) scanning electron microscope quickly. An electron beam was generated by a field emission gun. Characteristic X-ray radiation was detected by X-Flash 410-M (Bruker) and processed with QUANTAX 200 software package. Oxygen signals were not taken into account due to partial hydrolysis while inserting the sample.

**Electronic Structure Calculations:** The electronic band structure was calculated using the full-potential-linear-augmented plane-wave (FLAPW) method with the WIEN2k package.<sup>[28]</sup> Exchange and corre-

lation were treated with the PBE<sup>[29]</sup> or mBJ<sup>[30]</sup> functionals. The experimental lattice parameters and atom positions were used for the band and DOS calculations shown in Figure 6. Tentatively optimizations of the atom positions showed no significant changes.

## Acknowledgements

The authors thank C. Minke for assistance with the MAS-NMR measurements. Financial support by the Deutsche Forschungsgemeinschaft (DFG) is gratefully acknowledged.

**Keywords:** Phosphidosilicates; Enantiotropic phase transition; Pseudo edges; Barium; Semiconductors

## References

- [1] L. Toffoletti, H. Kirchhain, J. Landesfeind, W. Klein, L. van Wüllen, H. A. Gasteiger, T. F. Fässler, *Chem. Eur. J.* **2016**, *22*, 17635–17645.
- [2] B. Eisenmann, H. Jordan, H. Schäfer, *Mater. Res. Bull.* **1982**, *17*, 95–99.
- [3] J. Nuss, H. Kalpen, W. Hönl, M. Hartweg, H. G. von Schnering, *Z. Anorg. Allg. Chem.* **1997**, *623*, 205–211.
- [4] a) H. Eickhoff, L. Toffoletti, W. Klein, G. Raudaschl-Sieber, T. F. Fässler, *Inorg. Chem.* **2017**, *56*, 6688–6694; b) B. Eisenmann, M. Somer, *Z. Naturforsch. B* **1985**, *40*, 886–890.
- [5] B. Eisenmann, M. Somer, *Z. Naturforsch. B* **1984**, *39*, 736–738.
- [6] X. Zhang, T. Yu, C. Li, S. Wang, X. Tao, *Z. Anorg. Allg. Chem.* **2015**, *641*, 1545–1549.
- [7] K. Feng, L. Kang, W. Yin, W. Hao, Z. Lin, J. Yao, Y. Wu, *J. Solid State Chem.* **2013**, *205*, 129–133.
- [8] a) A. J. Springthorpe, J. G. Harrison, *Nature* **1969**, *222*, 977; b) A. A. Vaipolin, E. O. Osmanov, D. N. Tretyakov, *Inorg. Mater.* **1967**, *3*, 231–236.
- [9] H. Li, J. Kim, T. L. Groy, M. O’Keeffe, O. M. Yaghi, *J. Am. Chem. Soc.* **2001**, *123*, 4867–4868.
- [10] A. Haffner, T. Bräuniger, D. Johrendt, *Angew. Chem. Int. Ed.* **2016**, *55*, 13585–13588.
- [11] A. Haffner, A.-K. Hatz, I. Moudrakovski, B. V. Lotsch, D. Johrendt, *Angew. Chem. Int. Ed.* **2018**, *57*, 6155–6160.
- [12] T. Sasaki, H. Takizawa, K. Uheda, T. Yamashita, T. Endo, *J. Solid State Chem.* **2002**, *166*, 164–170.
- [13] F. Hiltmann, P. zum Hebel, A. Hammerschmidt, B. Krebs, *Z. Anorg. Allg. Chem.* **1993**, *619*, 293–302.
- [14] V. Weippert, A. Haffner, A. Stamatopoulos, D. Johrendt, *J. Am. Chem. Soc.* **2019**, *141*, 11245–11252.
- [15] a) H. Lin, J.-N. Shen, L. Chen, L.-M. Wu, *Inorg. Chem.* **2013**, *52*, 10726–10728; b) W. Khan, S. Goumri-Said, *RSC Adv.* **2015**, *5*, 9455–9461; c) H. Li, C. D. Malliakas, Z. Liu, J. A. Peters, H. Jin, C. D. Morris, L. Zhao, B. W. Wessels, A. J. Freeman, M. G. Kanatzidis, *Chem. Mater.* **2012**, *24*, 4434–4441; d) J. H. Liao, M. G. Kanatzidis, *Chem. Mater.* **1993**, *5*, 1561–1569; e) H.-W. Ma, G.-C. Guo, M.-S. Wang, G.-W. Zhou, S.-H. Lin, Z.-C. Dong, J.-S. Huang, *Inorg. Chem.* **2003**, *42*, 1366–1370.
- [16] H. G. von Schnering, G. Menge, *J. Solid State Chem.* **1979**, *28*, 13–19.
- [17] J. Mark, J. Wang, K. Wu, J. G. Lo, S. Lee, K. Kovnir, *J. Am. Chem. Soc.* **2019**, *141*, 11976–11983.
- [18] J. Mark, J.-A. Dolyniuk, N. Tran, K. Kovnir, *Z. Anorg. Allg. Chem.* **2019**, *645*, 242–247.
- [19] A. Haffner, D. Johrendt, *Z. Anorg. Allg. Chem.* **2017**, *643*, 1717–1720.
- [20] G. M. Sheldrick, *Acta Crystallogr., Sect. A* **2008**, *64*, 112–122.
- [21] H.-G. von Schnering, M. Wittmann, D. Sommer, *Z. Anorg. Allg. Chem.* **1984**, *510*, 61–71.

- [22] W. Büssem, H. Fischer, E. Gruner, *Naturwissenschaften* **1935**, *23*, 740.
- [23] A. Weiss, A. Weiss, *Z. Anorg. Allg. Chem.* **1954**, *276*, 95–112.
- [24] Bruker AXS Inc., APEX3 Version 2016.5–0, Madison, Wisconsin, **2016**.
- [25] Bruker AXS Inc., XPREP Version 2008/2, Karlsruhe, Germany, **2008**.
- [26] K. Brandenburg, Diamond Version 3.2k, Crystal Impact GbR, Bonn, Germany, **2014**.
- [27] A. Coelho, Topas Academic Version 4.1, Coelho Software, Brisbane, Australia, **2007**.
- [28] P. Blaha, K. Schwarz, G. K. H. Madsen, D. Kvasnicka, J. Luitz, Wien2k, An Augmented Plane Wave and Local Orbital Program for Calculating Crystal Properties, TU Wien, Vienna, Austria, ISBN3–9501031–1-2, 2006.
- [29] J. P. Perdew, S. Burke, M. Ernzerhof, *Phys. Rev. Lett.* **1996**, *77*, 3865–3868.
- [30] F. Tran, P. Blaha, *Phys. Rev. Lett.* **2009**, *102*, 226401.

---

Received: August 9, 2019

Published Online: November 8, 2019